

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3714	(381/191,174,113,369,178,355,190).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:03
L2	1805	L1 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:06
L3	38	L2 and (field adj effect adj transistor) and (resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:16
L4	29	3 and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:05
L5	11260	capacitor same ((field adj effect adj transistor) and (resistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:16
L6	8140	5 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:16
L7	14	L2 and (field adj effect adj transistor) with (resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:16
L8	3202	capacitor with ((field adj effect adj transistor) with (resistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:17

L9	2390	8 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:25
L10	3	9 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:17
L11	44	(capacitor same (field adj effect adj transistor) same (resistor)) same ((printed adj circuit adj board) PCB)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:30
L12	18	11 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:30
L13	3	(11 and 1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:27
L14	4	("5272758").PN. OR ("6512833"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/02 12:29
L15	2100	(capacitor and (field adj effect adj transistor) and (resistor)) and ((printed adj circuit adj board) PCB)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:30
L16	15	15 and 1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:30
L17	6	16 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 12:30

S1	816	(381/191).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 12:18
S2	816	S1 and ad@<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 12:19
S3	387	S1 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 13:00
S4	182	S3 and (electrode (electrode adj2 plate)) and (diaphragm membrane)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/07/26 12:20
S5	14	("4012604" "4117275" "4188513" "4392025" "4443666" "4453045" "4504703" "4571464" "5101543" "5272758" "5335286").PN. OR ("6594369"). URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/07/26 13:00
S6	3712	(381/191,174,113,369,178,355, 190).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 13:00
S7	1805	S6 and @ad<="20001121"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 13:01
S8	1	S7 and (field adj effect adj transistor) and (chip near5 capacitor) and (resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:03

S9	29	S7 and (field adj effect adj transistor) and (capacitor) and (resistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 12:05
S10	3	("3942029" "4626729" "5097515").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/07/26 14:18
S11	2	("3894199" "4730283").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/07/26 14:23
S12	338	himori.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 14:23
S13	1673	yasuno.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 14:24
S14	8	S12 and S13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/07/26 14:24
S15	4	("5272758").PN. OR ("6512833").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/07/26 14:30